

HAF2014

Silicon N Channel MOS FET Series Power Switching

R07DS0506EJ0400 (Previous: REJ03G1140-0300) Rev.4.00

Jul 08, 2011

Description

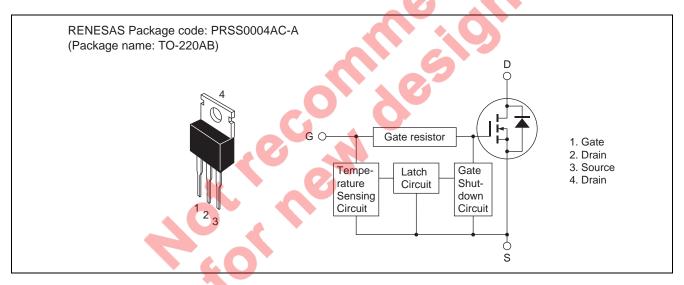
This FET has the over temperature shut-down capability sensing to the junction temperature.

This FET has the built-in over temperature shut-down circuit in the gate area. And this circuit operation to shut-down the gate voltage in case of high junction temperature like applying over power consumption, over current etc.

Features

- Logic level operation (4 to 6 V Gate drive)
- High endurance capability against to the short circuit
- Built-in the over temperature shut-down circuit
- Latch type shut-down operation (Need 0 voltage recovery)

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Value	Unit	
Drain to source voltage	V _{DSS}	60	V	
Gate to source voltage	V _{GSS}	16	V	
	V_{GSS}	-2.5	V	
Drain current	I _D	40	Α	
Drain peak current	I _{D (pulse)} Note 1	80	А	
Body-drain diode reverse drain current	I _{DR}	40	А	
Channel dissipation	Pch Note 2	50	W	
Channel temperature	Tch	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

Notes: 1. PW \leq 10 $\mu s,$ duty cycle \leq 1%

2. Value at Ta = 25°C

Typical Operation Characteristics

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Input voltage	V _{IH}	3.5	_	_	V	
	V _{IL}	_	_	1.2	V	
Input current	I _{IH1}	_	_	100	μΑ	$Vi = 8 V, V_{DS} = 0$
(Gate non shut down)	I _{IH2}	_	_	50	μΑ	$Vi = 3.5 V, V_{DS} = 0$
	I _{IL}	_	_	1	μΑ	$Vi = 1.2 V, V_{DS} = 0$
Input current	I _{IH (sd) 1}	_	0.8	_	mA	$Vi = 8 V, V_{DS} = 0$
(Gate shut down)	I _{IH (sd) 2}	_	0.35	_	mA	$Vi = 3.5 V, V_{DS} = 0$
Shut down temperature	Tsd	_	175	_	°C	Channel temperature
Gate operation voltage	V _{OP}	3.5	_	12	V	

Electrical Characteristics

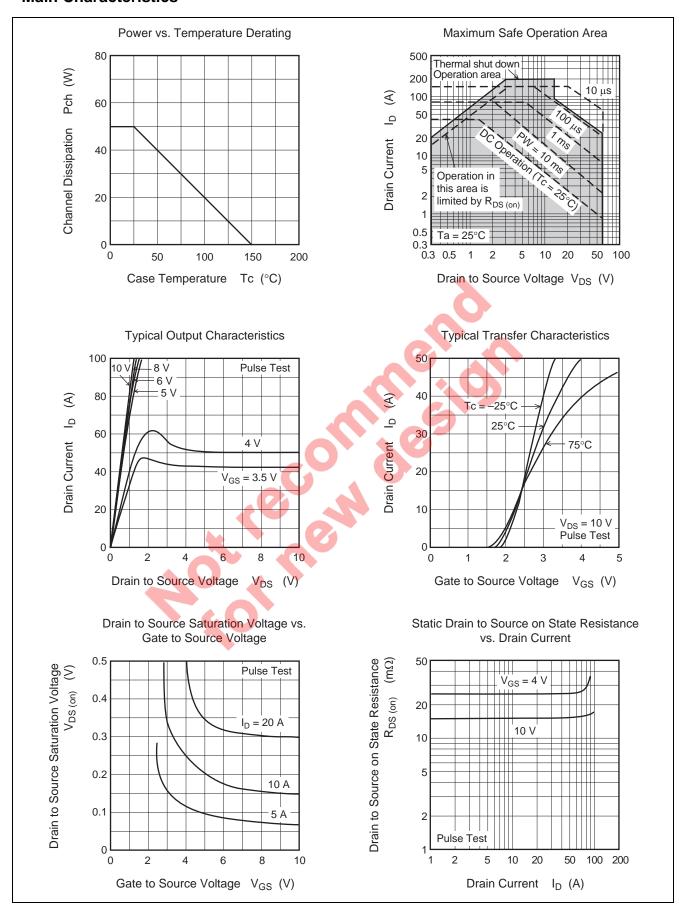
 $(Ta = 25^{\circ}C)$

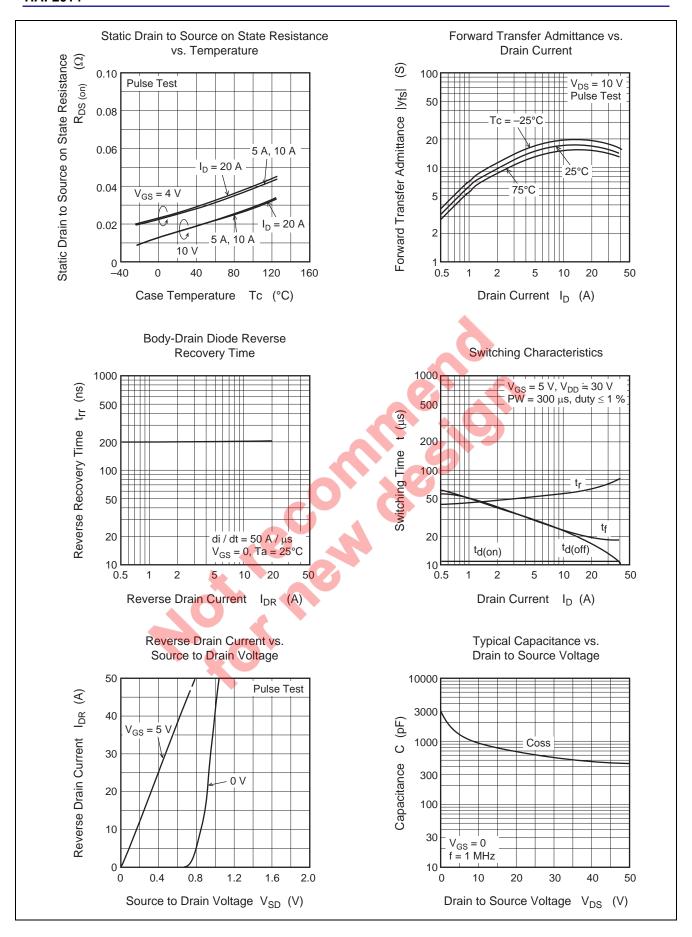
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain current	I _{D1}	15	_	- 5	Α	$V_{GS} = 3.5 \text{ V}, V_{DS} = 2 \text{ V}$
	I _{D2}	_	_	10	mA	$V_{GS} = 1.2 \text{ V}, V_{DS} = 2 \text{ V}$
Drain to source breakdown voltage	V _{(BR) DSS}	60	_		V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V _{(BR) GSS}	16	_		V	$I_G = 300 \mu A, V_{DS} = 0$
	V _{(BR) GSS}	-2.5		_	V	$I_G = -100 \mu A, V_{DS} = 0$
Gate to source leak current	I _{GSS1}	_		100	μΑ	$V_{GS} = 8 \text{ V}, V_{DS} = 0$
	I_{GSS2}	_		50	μΑ	$V_{GS} = 3.5 \text{ V}, V_{DS} = 0$
	I_{GSS3}	4	_		μΑ	$V_{GS} = 1.2 \text{ V}, V_{DS} = 0$
	I _{GSS4}		. 70	-100	μΑ	$V_{GS} = -2.4 \text{ V}, V_{DS} = 0$
Input current (shut down)	I _{GS (op) 1}		0.8	_	mA	$V_{GS} = 8 \text{ V}, V_{DS} = 0$
	I _{GS (op) 2}	_	0.35	_	mA	$V_{GS} = 3.5 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}			10	μΑ	$V_{DS} = 60 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	V _{GS (off)}	1.0	_	2.25	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to source on state resistance	R _{DS (on)}	-	25	33	mΩ	$I_D = 20 \text{ A}, V_{GS} = 4 \text{ V}^{\text{Note 3}}$
	R _{DS (on)}	/ –	15	20	mΩ	$I_D = 20 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note 3}}$
Forward transfer admittance	y _{fs}	8	16	_	S	$I_D = 20 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note 3}}$
Output capacitance	Coss	_	940	_	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0$
						f = 1 MHz
Turn-on delay time	t _{d (on)}	_	10.7	_	μS	I _D = 20 A
Rise time	t _r	_	66	_	μS	$V_{GS} = 5 V$
Turn-off delay time	t _{d (off)}	_	15.5	_	μS	$R_L = 1.5 \Omega$
Fall time	t _f	_	19	_	μS	
Body-drain diode forward voltage	V_{DF}	_	1	_	V	$I_F = 40 \text{ A}, V_{GS} = 0$
Body-drain diode reverse recovery time	t _{rr}	_	200	_	ns	I _F = 40 A, V _{GS} = 0
						$di_F/dt = 50 A/\mu s$
Over load shut down operation time Note4	t _{os1}	_	1	_	ms	$V_{GS} = 5 \text{ V}, V_{DD} = 16 \text{ V}$

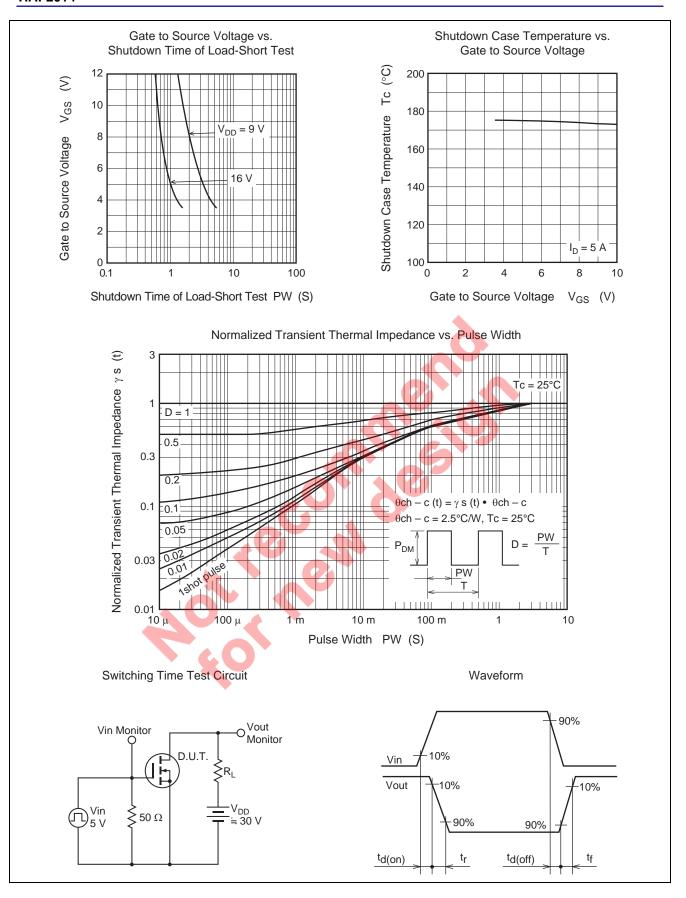
Notes: 3. Pulse test

4. Including the junction temperature rise of the over loaded condition.

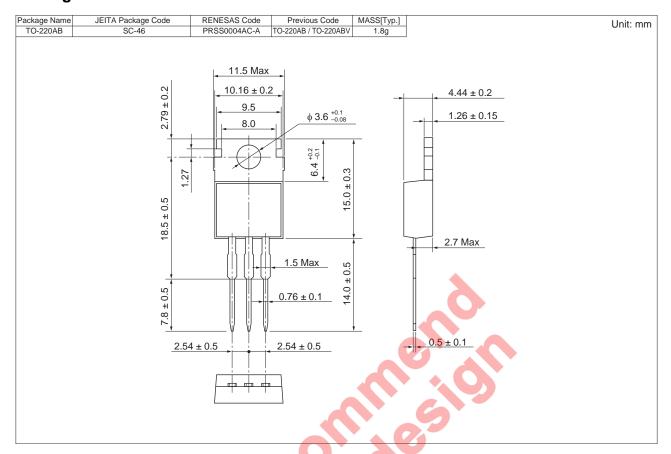
Main Characteristics







Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
HAF2014-90	Max: 50 pcs/sack	Sack

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